Unit: mm

1: Output 2: Common 3: Input

AN78Lxx/AN78LxxM Series

3-pin positive output voltage regulator (100 mA type)

■ Overview

The AN78Lxx series and the AN78LxxM series are 3pin fixed positive output type monolithic voltage regulator.

A stabilized fixed output voltage is obtained from an unstable DC input voltage without using any external parts. 12 types of fixed output voltage are available; 4V, 5V, 6V, 7V, 8V, 9V, 10V, 12V, 15V, 18V, 20V and 24V. They can be used widely as power circuits with a current capacity of up to 100mA.

■ Features

- No external components
- Output voltage: 4V,5V,6V,7V,8V,9V,10V,12V,15V, 18V,20V,24V
- Built-in overcurrent limit circuit
- Built-in thermal overload protection circuit

5.0±0.2 1.1 Input 2.2 Output 3.2 Common SSIP003-P-0000 AN78LxxM series 4.6 max. 1.8 max. 4.6 max. 1.8 max. 1.8 max. 1.8 max. 1.8 max.

AN78Lxx series

Note) The packages (SSIP003-P-0000 and HSIP003-P-0000B) of this product will be changed to lead-free type (SSIP003-P-0000S and HSIP003-P-0000Q). See the new package dimensions section later of this datasheet.

HSIP003-P-0000B

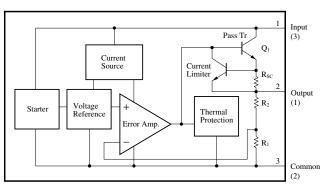
0.58 max.

3.0

1.5

0.48 max

■ Block Diagram (AN78Lxx series)



Note) The number in () shows the pin number for the AN78LxxM series.

■ Absolute Maximum Ratings at T_a = 25°C

Parameter		Symbol	Rating	Unit
Input voltage		V /	35 *1	V
		V_{I}	40 *2	V
Power dissipation	Power dissipation		650 *3	mW
Operating ambient ten	nperature	$T_{ m opr}$	-30 to +80	°C
Ctt	AN78Lxx series	T	-55 to +150	°C
Storage temperature	AN78LxxM series	T_{stg}	-55 to +125	°C

^{*1} AN78L04/M, AN78L05/M, AN78L06/M, AN78L07/M, AN78L08/M, AN78L09/M, AN78L10/M, AN78L12/M, AN78L15/M

■ Electrical Characteristics at T_a = 25°C

• AN78L04, AN78L04M (4V type)

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Output voltage	$V_{\rm o}$	$T_j = 25^{\circ}C$	3.84	4	4.16	V
Output voltage tolerance	Vo	$V_{\rm I} = 6.5 \text{ to } 19\text{V}, I_{\rm O} = 1 \text{ to } 70\text{mA}$	3.8		4.2	V
Line regulation	REG _{IN}	$V_I = 6.5 \text{ to } 19V, T_j = 25^{\circ}C$		50	145	mV
Line regulation	KEUIN	$V_{\rm I} = 7 \text{ to } 19 \text{V}, T_{\rm j} = 25^{\circ}\text{C}$		40	95	mV
I and manufaction	DEC	$I_0 = 1 \text{ to } 100\text{mA}, T_j = 25^{\circ}\text{C}$		10	55	mV
Load regulation	REG _L	$I_0 = 1 \text{ to } 40\text{mA}, T_j = 25^{\circ}\text{C}$		4.5	30	mV
Bias current	I_{Bias}	$T_j = 25$ °C		2	3	mA
Bias current fluctuation to input	$\Delta I_{Bias(IN)}$	$V_I = 7 \text{ to } 19V, T_j = 25^{\circ}C$			1	mA
Bias current fluctuation to load	$\Delta I_{Bias(L)}$	$I_0 = 1 \text{ to } 40\text{mA}, T_j = 25^{\circ}\text{C}$			0.1	mA
Output noise voltage	V _{no}	f = 10Hz to 100kHz		40		μV
Ripple rejection ratio	RR	$V_I = 7 \text{ to } 17V, I_O = 40\text{mA}, f = 120\text{Hz}$	48	58		dB
Minimum input/output voltage difference	$V_{\text{DIF}(\text{min})}$	$T_j = 25^{\circ}C$		1.7		V
Output short-circuit current	I _{O(Short)}	$T_j = 25^{\circ}C, V_I = 35V$		140	_	mA
Output voltage temperature coefficient	$\Delta V_O/T_a$	$I_0 = 5 \text{mA}, T_j = 0 \text{ to } 125^{\circ}\text{C}$		- 0.6		mV/°C

Note 1) The specified condition $T_j = 25^{\circ}$ C means that the test should be carried out within so short a test time (within 10ms) that the characteristic value drift due to the chip junction temperature rise can be ignored.

^{*2} AN78L18/M, AN78L20/M, AN78L24/M

^{*3} Follow the derating curve. When T_j exceeds 150°C, the internal circuit cuts off the output.

AN78LxxM series is mounted on a standard board (glass epoxy: 20mm × 20mm × t1.7mm with Cu foil of 1cm² or more).

Note 2) Unless otherwise specified, $V_I = 9V$, $I_O = 40 \text{mA}$, $C_I = 0.33 \mu\text{F}$, $C_O = 0.1 \mu\text{F}$, $T_j = 0$ to 125°C (AN78L04) and $T_j = 0$ to 100°C (AN78L04M)

• AN78L05, AN78L05M (5V type)

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Output voltage	V_{O}	$T_j = 25^{\circ}C$	4.8	5	5.2	V
Output voltage tolerance	V_{O}	$V_I = 7.5 \text{ to } 20V, I_O = 1 \text{ to } 70\text{mA}$	4.75		5.25	V
Line regulation	REG_{IN}	$V_I = 7.5 \text{ to } 20V, T_j = 25^{\circ}C$		55	150	mV
Line regulation	KEGIN	$V_I = 8 \text{ to } 20V, T_j = 25^{\circ}C$		45	100	mV
Load regulation	DEC	$I_0 = 1 \text{ to } 100 \text{mA}, T_j = 25^{\circ}\text{C}$		11	60	mV
Load regulation	REG _L	$I_0 = 1 \text{ to } 40\text{mA}, T_j = 25^{\circ}\text{C}$		5	30	mV
Bias current	I_{Bias}	$T_j = 25^{\circ}C$		2	3	mA
Bias current fluctuation to input	$\Delta I_{Bias(IN)}$	$V_I = 8 \text{ to } 20V, T_j = 25^{\circ}C$			1	mA
Bias current fluctuation to load	$\Delta I_{Bias(L)}$	$I_0 = 1 \text{ to } 40\text{mA}, T_j = 25^{\circ}\text{C}$			0.1	mA
Output noise voltage	V_{no}	f = 10Hz to $100kHz$		40		μV
Ripple rejection ratio	RR	$V_I = 8 \text{ to } 18V, I_O = 40\text{mA}, f = 120\text{Hz}$	47	57		dB
Minimum input/output voltage difference	$V_{\text{DIF}(\text{min})}$	$T_j = 25^{\circ}C$		1.7		V
Output short-circuit current	I _{O(Short)}	$T_j = 25^{\circ}C, V_I = 35V$	_	140	_	mA
Output voltage temperature coefficient	$\Delta V_O/T_a$	$I_0 = 5 \text{mA}, T_j = 0 \text{ to } 125^{\circ}\text{C}$	_	- 0.65		mV/°C

Note 1) The specified condition $T_j = 25^{\circ}$ C means that the test should be carried out within so short a test time (within 10ms) that the characteristic value drift due to the chip junction temperature rise can be ignored.

• AN78L06, AN78L06M (6V type)

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Output voltage	V_{O}	$T_j = 25^{\circ}C$	5.76	6	6.24	V
Output voltage tolerance	V_{O}	$V_I = 8.5 \text{ to } 21V, I_O = 1 \text{ to } 70\text{mA}$	5.7		6.3	V
Line regulation	REG _{IN}	$V_I = 8.5 \text{ to } 21V, T_j = 25^{\circ}C$		60	155	mV
Eme regulation	KEUIN	$V_I = 9 \text{ to } 21V, T_j = 25^{\circ}C$		50	105	mV
Load regulation	REG	$I_0 = 1 \text{ to } 100\text{mA}, T_j = 25^{\circ}\text{C}$		12	65	mV
Load regulation	REG _L	$I_0 = 1 \text{ to } 40\text{mA}, T_j = 25^{\circ}\text{C}$		5.5	35	mV
Bias current	I_{Bias}	$T_j = 25^{\circ}C$		2	3	mA
Bias current fluctuation to input	$\Delta I_{Bias(IN)}$	$V_I = 9 \text{ to } 21V, T_j = 25^{\circ}C$			1	mA
Bias current fluctuation to load	$\Delta I_{Bias(L)}$	$I_0 = 1 \text{ to } 40\text{mA}, T_j = 25^{\circ}\text{C}$			0.1	mA
Output noise voltage	V_{no}	f = 10Hz to 100kHz		50		μV
Ripple rejection ratio	RR	$V_I = 9 \text{ to } 19V, I_O = 40\text{mA}, f = 120\text{Hz}$	46	56		dB
Minimum input/output voltage difference	$V_{\text{DIF}(\text{min})}$	$T_j = 25^{\circ}C$		1.7		V
Output short-circuit current	$I_{O(Short)}$	$T_j = 25^{\circ}C, V_I = 35V$		140		mA
Output voltage temperature coefficient	$\Delta V_O/T_a$	$I_0 = 5 \text{mA}, T_j = 0 \text{ to } 125^{\circ}\text{C}$	_	- 0.7		mV/°C

Note 1) The specified condition $T_j = 25^{\circ}C$ means that the test should be carried out within so short a test time (within 10ms) that the characteristic value drift due to the chip junction temperature rise can be ignored.

Note 2) Unless otherwise specified, $V_I = 11V$, $\hat{I}_O = 40 \text{mA}$, $C_I = 0.33 \mu\text{F}$, $C_O = 0.1 \mu\text{F}$, $T_j = 0$ to 125°C (AN78L06) and $T_j = 0$ to 100°C (AN78L06M)

Note 2) Unless otherwise specified, $V_I = 10V$, $I_O = 40 \text{mA}$, $C_I = 0.33 \mu\text{F}$, $C_O = 0.1 \mu\text{F}$, $T_j = 0$ to 125°C (AN78L05) and $T_j = 0$ to 100°C (AN78L05M)

• AN78L07, AN78L07M (7V type)

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Output voltage	V_{O}	$T_j = 25^{\circ}C$	6.72	7	7.28	V
Output voltage tolerance	V_{O}	$V_{\rm I} = 9.5 \text{ to } 22\text{V}, I_{\rm O} = 1 \text{ to } 70\text{mA}$	6.65		7.35	V
Line regulation	REG _{IN}	$V_I = 9.5 \text{ to } 22V, T_j = 25^{\circ}C$		70	165	mV
Line regulation	KEGIN	$V_{\rm I} = 10 \text{ to } 22\text{V}, T_{\rm j} = 25^{\circ}\text{C}$		60	115	mV
Lond regulation	DEC	$I_0 = 1 \text{ to } 100\text{mA}, T_j = 25^{\circ}\text{C}$		13	75	mV
Load regulation	REG _L	$I_0 = 1 \text{ to } 40\text{mA}, T_j = 25^{\circ}\text{C}$		6	35	mV
Bias current	I_{Bias}	$T_j = 25^{\circ}C$		2	3	mA
Bias current fluctuation to input	$\Delta I_{Bias(IN)}$	$V_{\rm I} = 10 \text{ to } 22 \text{V}, T_{\rm j} = 25 ^{\circ} \text{C}$			1	mA
Bias current fluctuation to load	$\Delta I_{Bias(L)}$	$I_0 = 1 \text{ to } 40\text{mA}, T_j = 25^{\circ}\text{C}$			0.1	mA
Output noise voltage	V_{no}	f = 10Hz to 100kHz		50		μV
Ripple rejection ratio	RR	$V_I = 10 \text{ to } 20V, I_O = 40\text{mA}, f = 120\text{Hz}$	45	55		dB
Minimum input/output voltage difference	$V_{\text{DIF}(\text{min})}$	$T_j = 25^{\circ}C$	_	1.7	_	V
Output short-circuit current	$I_{O(Short)}$	$T_j = 25^{\circ}C, V_I = 35V$		140	_	mA
Output voltage temperature coefficient	$\Delta V_{O}/T_{a}$	$I_0 = 5 \text{mA}, T_j = 0 \text{ to } 125^{\circ}\text{C}$	_	- 0.75		mV/°C

Note 1) The specified condition $T_j = 25^{\circ}C$ means that the test should be carried out within so short a test time (within 10ms) that the characteristic value drift due to the chip junction temperature rise can be ignored.

• AN78L08, AN78L08M (8V type)

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Output voltage	V_{O}	$T_j = 25^{\circ}C$	7.7	8	8.3	V
Output voltage tolerance	V_{O}	$V_I = 10.5 \text{ to } 23V, I_O = 1 \text{ to } 70\text{mA}$	7.6		8.4	V
Line regulation	REGIN	$V_I = 10.5 \text{ to } 23\text{V}, T_j = 25^{\circ}\text{C}$		80	175	mV
Line regulation	KEGIN	$V_I = 11 \text{ to } 23V, T_j = 25^{\circ}C$		70	125	mV
Load ragulation	DEC	$I_0 = 1 \text{ to } 100\text{mA}, T_j = 25^{\circ}\text{C}$		15	80	mV
Load regulation	REG _L	$I_0 = 1 \text{ to } 40\text{mA}, T_j = 25^{\circ}\text{C}$		7	40	mV
Bias current	I_{Bias}	$T_j = 25^{\circ}C$		2	3	mA
Bias current fluctuation to input	$\Delta I_{Bias(IN)}$	$V_I = 11 \text{ to } 23V, T_j = 25^{\circ}C$			1	mA
Bias current fluctuation to load	$\Delta I_{Bias(L)}$	$I_0 = 1 \text{ to } 40\text{mA}, T_j = 25^{\circ}\text{C}$			0.1	mA
Output noise voltage	V_{no}	f = 10Hz to 100kHz		60	_	μV
Ripple rejection ratio	RR	$V_I = 11 \text{ to } 21V, I_O = 40\text{mA}, f = 120\text{Hz}$	44	54		dB
Minimum input/output voltage difference	$V_{\text{DIF}(\text{min})}$	$T_j = 25^{\circ}C$		1.7		V
Output short-circuit current	I _{O(Short)}	$T_j = 25^{\circ}C, V_I = 35V$		140	_	mA
Output voltage temperature coefficient	$\Delta V_{O}/T_{a}$	$I_0 = 5 \text{mA}, T_j = 0 \text{ to } 125^{\circ}\text{C}$		- 0.8	_	mV/°C

Note 1) The specified condition $T_j = 25^{\circ}C$ means that the test should be carried out within so short a test time (within 10ms) that the characteristic value drift due to the chip junction temperature rise can be ignored.

Note 2) Unless otherwise specified, $V_I = 12V$, $I_O = 40mA$, $C_I = 0.33\mu F$, $C_O = 0.1\mu F$, $T_j = 0$ to $125^{\circ}C$ (AN78L07) and $T_j = 0$ to $100^{\circ}C$ (AN78L07M)

Note 2) Unless otherwise specified, $V_I = 14V$, $I_O = 40 \text{mA}$, $C_I = 0.33 \mu\text{F}$, $C_O = 0.1 \mu\text{F}$, $T_j = 0$ to 125°C (AN78L08) and $T_j = 0$ to 100°C (AN78L08M)

• AN78L09, AN78L09M (9V type)

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Output voltage	V_{O}	$T_j = 25^{\circ}C$	8.64	9	9.35	V
Output voltage tolerance	V_{O}	$V_I = 11.5 \text{ to } 24V, I_O = 1 \text{ to } 70\text{mA}$	8.55		9.45	V
Line regulation	REG_{IN}	$V_I = 11.5 \text{ to } 24V, T_j = 25^{\circ}C$		90	190	mV
Line regulation	KLOIN	$V_I = 12 \text{ to } 24V, T_j = 25^{\circ}C$		80	140	mV
Load regulation	REG _I	$I_0 = 1 \text{ to } 100 \text{mA}, T_j = 25^{\circ}\text{C}$		16	85	mV
Load regulation	REGL	$I_0 = 1 \text{ to } 40\text{mA}, T_j = 25^{\circ}\text{C}$	_	8	45	mV
Bias current	I_{Bias}	$T_j = 25^{\circ}C$		2	3	mA
Bias current fluctuation to input	$\Delta I_{Bias(IN)}$	$V_I = 12 \text{ to } 24V, T_j = 25^{\circ}C$		_	1	mA
Bias current fluctuation to load	$\Delta I_{Bias(L)}$	$I_0 = 1 \text{ to } 40\text{mA}, T_j = 25^{\circ}\text{C}$			0.1	mA
Output noise voltage	V_{no}	f = 10Hz to 100kHz		65		μV
Ripple rejection ratio	RR	$V_I = 12 \text{ to } 22V, I_O = 40\text{mA}, f = 120\text{Hz}$	43	53	_	dB
Minimum input/output voltage difference	$V_{\text{DIF}(\text{min})}$	$T_j = 25^{\circ}C$		1.7		V
Output short-circuit current	$I_{O(Short)}$	$T_j = 25^{\circ}C, V_I = 35V$		140		mA
Output voltage temperature coefficient	$\Delta V_{O}/T_{a}$	$I_0 = 5 \text{mA}, T_j = 0 \text{ to } 125^{\circ}\text{C}$	_	- 0.85	_	mV/°C

Note 1) The specified condition $T_j = 25^{\circ}$ C means that the test should be carried out within so short a test time (within 10ms) that the characteristic value drift due to the chip junction temperature rise can be ignored.

AN78L10, AN78L10M (10V type)

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Output voltage	V_{O}	$T_j = 25^{\circ}C$	9.6	10	10.4	V
Output voltage tolerance	Vo	$V_I = 12.5 \text{ to } 25V, I_O = 1 \text{ to } 70\text{mA}$	9.5		10.5	V
Line regulation	REG _{IN}	$V_I = 12.5 \text{ to } 25V, T_j = 25^{\circ}C$		100	210	mV
Line regulation	KEOIN	$V_I = 13 \text{ to } 25V, T_j = 25^{\circ}C$		90	160	mV
Load regulation	DEC	$I_0 = 1 \text{ to } 100\text{mA}, T_j = 25^{\circ}\text{C}$		17	90	mV
Load regulation	REG _L	$I_0 = 1 \text{ to } 40\text{mA}, T_j = 25^{\circ}\text{C}$		9	45	mV
Bias current	I_{Bias}	$T_j = 25^{\circ}C$		2	3	mA
Bias current fluctuation to input	$\Delta I_{Bias(IN)}$	$V_I = 13 \text{ to } 25V, T_j = 25^{\circ}C$			1	mA
Bias current fluctuation to load	$\Delta I_{Bias(L)}$	$I_0 = 1 \text{ to } 40\text{mA}, T_j = 25^{\circ}\text{C}$			0.1	mA
Output noise voltage	V_{no}	f = 10Hz to 100kHz		70		μV
Ripple rejection ratio	RR	$V_I = 13 \text{ to } 23V, I_O = 40\text{mA}, f = 120\text{Hz}$	42	52		dB
Minimum input/output voltage difference	$V_{\text{DIF}(\text{min})}$	$T_j = 25^{\circ}C$		1.7		V
Output short-circuit current	I _{O(Short)}	$T_j = 25^{\circ}C, V_I = 35V$		140	_	mA
Output voltage temperature coefficient	$\Delta V_O/T_a$	$I_0 = 5 \text{mA}, T_j = 0 \text{ to } 125^{\circ}\text{C}$	_	- 0.9	_	mV/°C

Note 1) The specified condition $T_j = 25^{\circ}$ C means that the test should be carried out within so short a test time (within 10ms) that the characteristic value drift due to the chip junction temperature rise can be ignored.

Note 2) Unless otherwise specified, $V_I = 16V$, $\hat{I}_0 = 40 \text{mA}$, $C_I = 0.33 \mu\text{F}$, $C_0 = 0.1 \mu\text{F}$, $T_j = 0$ to 125°C (AN78L10) and $T_j = 0$ to 100°C (AN78L10M)

Note 2) Unless otherwise specified, $V_I = 15V$, $I_O = 40 \text{mA}$, $C_I = 0.33 \mu\text{F}$, $C_O = 0.1 \mu\text{F}$, $T_j = 0$ to 125°C (AN78L09) and $T_j = 0$ to 100°C (AN78L09M)

• AN78L12, AN78L12M (12V type)

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Output voltage	Vo	$T_j = 25^{\circ}C$	11.5	12	12.5	V
Output voltage tolerance	Vo	$V_I = 14.5 \text{ to } 27V, I_O = 1 \text{ to } 70\text{mA}$	11.4		12.6	V
Line regulation	REG _{IN}	$V_I = 14.5 \text{ to } 27V, T_j = 25^{\circ}C$		120	250	mV
Line regulation	KEOIN	$V_I = 15 \text{ to } 27V, T_j = 25^{\circ}C$		100	200	mV
Load ragulation	DEC	$I_0 = 1 \text{ to } 100\text{mA}, T_j = 25^{\circ}\text{C}$		20	100	mV
Load regulation	REG _L	$I_0 = 1 \text{ to } 40\text{mA}, T_j = 25^{\circ}\text{C}$		10	50	mV
Bias current	I_{Bias}	$T_j = 25^{\circ}C$		2	3.5	mA
Bias current fluctuation to input	$\Delta I_{Bias(IN)}$	$V_I = 15 \text{ to } 27V, T_j = 25^{\circ}C$			1	mA
Bias current fluctuation to load	$\Delta I_{Bias(L)}$	$I_0 = 1 \text{ to } 40\text{mA}, T_j = 25^{\circ}\text{C}$			0.1	mA
Output noise voltage	V_{no}	f = 10Hz to 100kHz		80		μV
Ripple rejection ratio	RR	$V_I = 15 \text{ to } 25\text{V}, I_O = 40\text{mA}, f = 120\text{Hz}$	40	50		dB
Minimum input/output voltage difference	$V_{\text{DIF}(\text{min})}$	$T_j = 25^{\circ}C$		1.7		V
Output short-circuit current	I _{O(Short)}	$T_j = 25^{\circ}C, V_I = 35V$		140	_	mA
Output voltage temperature coefficient	$\Delta V_O/T_a$	$I_0 = 5 \text{mA}, T_j = 0 \text{ to } 125^{\circ}\text{C}$		-1		mV/°C

Note 1) The specified condition $T_j = 25^{\circ}$ C means that the test should be carried out within so short a test time (within 10ms) that the characteristic value drift due to the chip junction temperature rise can be ignored.

AN78L15, AN78L15M (15V type)

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Output voltage	V_{O}	$T_j = 25^{\circ}C$	14.4	15	15.6	V
Output voltage tolerance	Vo	$V_I = 17.5 \text{ to } 30\text{V}, I_O = 1 \text{ to } 70\text{mA}$	14.25		15.75	V
Line regulation	REG _{IN}	$V_I = 17.5 \text{ to } 30\text{V}, T_j = 25^{\circ}\text{C}$		130	300	mV
Line regulation	KEOIN	$V_I = 18 \text{ to } 30V, T_j = 25^{\circ}C$		110	250	mV
Lond regulation	REG _I	$I_0 = 1 \text{ to } 100\text{mA}, T_j = 25^{\circ}\text{C}$		25	150	mV
Load regulation	KEG _L	$I_0 = 1 \text{ to } 40\text{mA}, T_j = 25^{\circ}\text{C}$		12	75	mV
Bias current	I_{Bias}	$T_j = 25^{\circ}C$		2	3.5	mA
Bias current fluctuation to input	$\Delta I_{Bias(IN)}$	$V_I = 18 \text{ to } 30V, T_j = 25^{\circ}C$		_	1	mA
Bias current fluctuation to load	$\Delta I_{Bias(L)}$	$I_0 = 1 \text{ to } 40\text{mA}, T_j = 25^{\circ}\text{C}$			0.1	mA
Output noise voltage	V_{no}	f = 10Hz to 100kHz		90		μV
Ripple rejection ratio	RR	$V_I = 18 \text{ to } 28V, I_O = 40\text{mA}, f = 120\text{Hz}$	38	48		dB
Minimum input/output voltage difference	$V_{\text{DIF}(\text{min})}$	$T_j = 25^{\circ}C$		1.7		V
Output short-circuit current	I _{O(Short)}	$T_j = 25^{\circ}C, V_I = 35V$		140	_	mA
Output voltage temperature coefficient	$\Delta V_O/T_a$	$I_0 = 5 \text{mA}, T_j = 0 \text{ to } 125^{\circ}\text{C}$	_	-1.3	_	mV/°C

Note 1) The specified condition $T_j = 25^{\circ}$ C means that the test should be carried out within so short a test time (within 10ms) that the characteristic value drift due to the chip junction temperature rise can be ignored.

Note 2) Unless otherwise specified, $V_I = 19V$, $\hat{I}_O = 40 \text{mA}$, $C_I = 0.33 \mu\text{F}$, $C_O = 0.1 \mu\text{F}$, $T_j = 0$ to 125°C (AN78L12) and $T_j = 0$ to 100°C (AN78L12M)

Note 2) Unless otherwise specified, $V_I = 23V$, $I_O = 40mA$, $C_I = 0.33\mu F$, $C_O = 0.1\mu F$, $T_j = 0$ to $125^{\circ}C$ (AN78L15) and $T_j = 0$ to $100^{\circ}C$ (AN78L15M)

• AN78L18, AN78L18M (18V type)

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Output voltage	V_{O}	$T_j = 25^{\circ}C$	17.3	18	18.7	V
Output voltage tolerance	V_{O}	$V_I = 20.5 \text{ to } 33\text{V}, I_O = 1 \text{ to } 70\text{mA}$	17.1	_	18.9	V
Line regulation	REG _{IN}	$V_I = 20.5 \text{ to } 33V, T_j = 25^{\circ}C$		45	300	mV
Line regulation	KEGIN	$V_I = 21 \text{ to } 33V, T_j = 25^{\circ}C$		35	250	mV
Lond regulation	DEC	$I_0 = 1 \text{ to } 100\text{mA}, T_j = 25^{\circ}\text{C}$		30	170	mV
Load regulation	REG _L	$I_0 = 1 \text{ to } 40\text{mA}, T_j = 25^{\circ}\text{C}$		15	85	mV
Bias current	I_{Bias}	$T_j = 25^{\circ}C$		2	3.5	mA
Bias current fluctuation to input	$\Delta I_{Bias(IN)}$	$V_I = 21 \text{ to } 33V, T_j = 25^{\circ}C$			1	mA
Bias current fluctuation to load	$\Delta I_{Bias(L)}$	$I_0 = 1 \text{ to } 40\text{mA}, T_j = 25^{\circ}\text{C}$			0.1	mA
Output noise voltage	V_{no}	f = 10Hz to 100kHz		150		μV
Ripple rejection ratio	RR	$V_I = 21 \text{ to } 31\text{V}, I_O = 40\text{mA}, f = 120\text{Hz}$	36	46		dB
Minimum input/output voltage difference	$V_{\text{DIF}(\text{min})}$	$T_j = 25^{\circ}C$		1.7		V
Output short-circuit current	I _{O(Short)}	$T_j = 25^{\circ}C, V_I = 35V$		140		mA
Output voltage temperature coefficient	$\Delta V_O/T_a$	$I_0 = 5 \text{mA}, T_j = 0 \text{ to } 125^{\circ}\text{C}$	_	-1.5	_	mV/°C

Note 1) The specified condition $T_j = 25^{\circ}$ C means that the test should be carried out within so short a test time (within 10ms) that the characteristic value drift due to the chip junction temperature rise can be ignored.

AN78L20, AN78L20M (20V type)

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Output voltage	V_{O}	$T_j = 25^{\circ}C$	19.2	20	20.8	V
Output voltage tolerance	Vo	$V_I = 22.5 \text{ to } 35\text{V}, I_O = 1 \text{ to } 70\text{mA}$	19		21	V
Line regulation	REG _{IN}	$V_I = 22.5 \text{ to } 35\text{V}, T_j = 25^{\circ}\text{C}$		50	300	mV
Line regulation	KEG _{IN}	$V_I = 23 \text{ to } 35\text{V}, T_j = 25^{\circ}\text{C}$		40	250	mV
Load ragulation	REG _I	$I_0 = 1 \text{ to } 100 \text{mA}, T_j = 25^{\circ}\text{C}$		35	180	mV
Load regulation	KEG _L	$I_0 = 1 \text{ to } 40\text{mA}, T_j = 25^{\circ}\text{C}$		17	90	mV
Bias current	I_{Bias}	$T_j = 25^{\circ}C$		2	3.5	mA
Bias current fluctuation to input	$\Delta I_{Bias(IN)}$	$V_I = 23 \text{ to } 35\text{V}, T_j = 25^{\circ}\text{C}$			1	mA
Bias current fluctuation to load	$\Delta I_{Bias(L)}$	$I_0 = 1 \text{ to } 40\text{mA}, T_j = 25^{\circ}\text{C}$		_	0.1	mA
Output noise voltage	V_{no}	f = 10Hz to 100kHz		170		μV
Ripple rejection ratio	RR	$V_I = 23 \text{ to } 33\text{V}, I_O = 40\text{mA}, f = 120\text{Hz}$	34	44		dB
Minimum input/output voltage difference	V _{DIF(min)}	$T_j = 25^{\circ}C$		1.7		V
Output short-circuit current	$I_{O(Short)}$	$T_j = 25^{\circ}C, V_I = 35V$		140	_	mA
Output voltage temperature coefficient	$\Delta V_O/T_a$	$I_0 = 5 \text{mA}, T_j = 0 \text{ to } 125^{\circ}\text{C}$		-1.7		mV/°C

Note 1) The specified condition $T_j = 25^{\circ}C$ means that the test should be carried out within so short a test time (within 10ms) that the characteristic value drift due to the chip junction temperature rise can be ignored.

Note 2) Unless otherwise specified, $V_I = 27V$, $\hat{I}_O = 40 \text{mA}$, $C_I = 0.33 \mu\text{F}$, $C_O = 0.1 \mu\text{F}$, $T_j = 0$ to 125°C (AN78L18) and $T_j = 0$ to 100°C (AN78L18M)

Note 2) Unless otherwise specified, $V_I = 29V$, $\hat{I}_O = 40mA$, $C_I = 0.33\mu F$, $C_O = 0.1\mu F$, $T_j = 0$ to $125^{\circ}C$ (AN78L20) and $T_j = 0$ to $100^{\circ}C$ (AN78L20M)

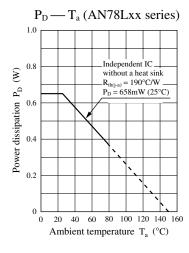
• AN78L24, AN78L24M (24V type)

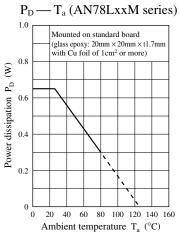
Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Output voltage	Vo	$T_j = 25^{\circ}C$	23	24	25	V
Output voltage tolerance	V_{O}	$V_I = 26.5 \text{ to } 39V, I_O = 1 \text{ to } 70\text{mA}$	22.8		25.2	V
Line regulation	REG _{IN}	$V_I = 26.5 \text{ to } 39V, T_j = 25^{\circ}C$		60	300	mV
		$V_I = 27 \text{ to } 39V, T_j = 25^{\circ}C$		50	250	mV
Load regulation	REG _L	$I_0 = 1 \text{ to } 100 \text{mA}, T_j = 25^{\circ}\text{C}$		40	200	mV
		$I_0 = 1 \text{ to } 40\text{mA}, T_j = 25^{\circ}\text{C}$		20	100	mV
Bias current	I_{Bias}	$T_j = 25^{\circ}C$		2	3.5	mA
Bias current fluctuation to input	$\Delta I_{Bias(IN)}$	$V_{I} = 27 \text{ to } 39V, T_{j} = 25^{\circ}C$			1	mA
Bias current fluctuation to load	$\Delta I_{Bias(L)}$	$I_0 = 1 \text{ to } 40\text{mA}, T_j = 25^{\circ}\text{C}$		_	0.1	mA
Output noise voltage	V_{no}	f = 10Hz to 100kHz		200		μV
Ripple rejection ratio	RR	$V_I = 27 \text{ to } 37V, I_O = 40\text{mA}, f = 120\text{Hz}$	34	44		dB
Minimum input/output voltage difference	$V_{\text{DIF}(min)}$	T _j = 25℃		1.7	_	V
Output short-circuit current	I _{O(Short)}	$T_j = 25^{\circ}C, V_I = 35V$		140		mA
Output voltage temperature coefficient	$\Delta V_{O}/T_{a}$	$I_0 = 5$ mA, $T_j = 0$ to 125 °C		-2		mV/°C

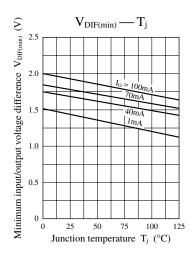
Note 1) The specified condition $T_j = 25^{\circ}C$ means that the test should be carried out within so short a test time (within 10ms) that the characteristic value drift due to the chip junction temperature rise can be ignored.

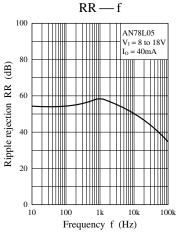
Note 2) Unless otherwise specified, $V_I = 33V$, $I_O = 40 \text{mA}$, $C_I = 0.33 \mu\text{F}$, $C_O = 0.1 \mu\text{F}$, $T_j = 0$ to 125°C (AN78L24) and $T_j = 0$ to 100°C (AN78L24M)

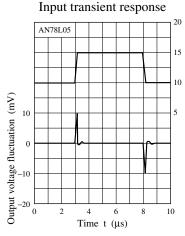
■ Main Characteristics

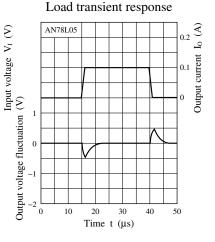


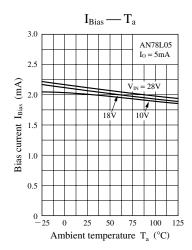




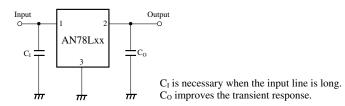








■ Basic Regulator Circuit



■ Usage Notes

1. Cautions for a basic circuit

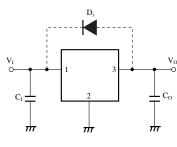


Figure 1

- C_I : When a wiring from a smoothing circuit to a three-pin regulator is long, it is likely to oscillate at output. A capacitor of $0.1\mu F$ to $0.47\mu F$ should be connected near an input pin.
- C_{O} : When any sudden change of load current is likely to occur, connect an electrolytic capacitor of $10\mu F$ to $100\mu F$ to improve a transitional response of output voltage.
- D_i: Normally unnecessary. But add it in the case that there is a residual voltage at the output capacitor Co even after switching off the supply power because a current is likely to flow into an output pin of the IC and damage the IC.

2. Other caution items

1) Short-circuit between the input pin and GND pin

If the input pin is short-circuitted to GND or is cut off when a large capacitance capacitor has been connected to the IC's load, a voltage of a capacitor connected to an output pin is applied between input/output of the IC and this likely results in damage of the IC. It is necessary, therefore, to connect a diode, as shown in figure 2, to counter the reverse bias between input/output pins.

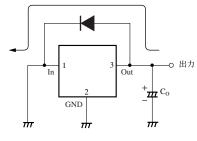
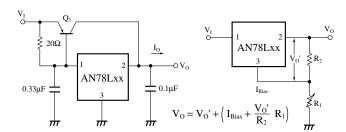


Figure 2

2) Floating of GND pin

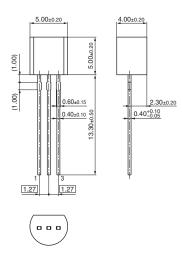
If a GND pin is made floating in an operating mode, an unstabilized input voltage is outputted. In this case, a thermal protection circuit inside the IC does not normally operate. In this state, if the load is short-circuited or overloaded, it is likely to damage the IC.

■ Application Circuit Examples

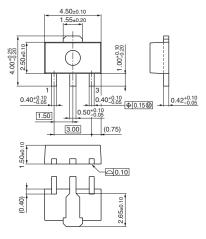


Note) V_0 varies due to sample to sample variation of I_{Bias} . Never fail to adjust individually with R_1 .

- New Package Dimensions (Unit: mm)
- SSIP003-P-0000S (Lead-free package)



• HSIP003-P-0000Q (Lead-free package)



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